

# 1N4001 thru 1N4007

REV. 9, MAY-2015, KDAC01

#### **REVERSE VOLTAGE – 50 to 1000 Volts** PLASTIC SILICON RECTIFIERS **FORWARD CURRENT – 1.0 Ampere FEATURES** DO - 41 · Low cost Diffused junction А В А · Low forward voltage drop · Low reverse leakage current • High current capability - C A D **MECHANICAL DATA** • Case: JEDEC DO-41, molding compound has DO - 41 UL flammability classification 94V-0 MAX DIM MIN • Polarity: Color band denotes cathode Α 25.4 5.20 В 4.10 • Weight: 0.012 ounces, 0.34 grams С 0.71 Ø 0.86 Ø Mounting Position: Any D 2.00 Ø 2.70 Ø All dimension in millimeter

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

ABSOLUTE RATINGS										
PARAMETER		SYMBOL	1N4001	1N4002	1N4003	1N4004	1N4005	1N4006	1N4007	UNIT
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Maximum DC blocking voltage		V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Average rectified output current per device @T <sub>A</sub> =75 <sup>°</sup> C		I <sub>(AV)</sub>	1.0					Α		
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	30					А		
$I^2$ t rating for fusing (t = 8.3ms)		l²t	3.7					A <sup>2</sup> S		
Operating temperature range		TJ	-55 to +125					°C		
Storage temperature range		T <sub>STG</sub>	-55 to +150					°C		
STATIC ELECTRICAL	CHARACTERISTICS									
PARAMETER	TEST CONDITION	SYMBOL	. MAX.				UNIT			

Forward voltage	I <sub>F</sub> = 1.0A	T <sub>J</sub> = 25°C	V <sub>F</sub>	1.0	V
Leakage current	$V_{R}$ at rated	T <sub>J</sub> = 25°C T <sub>J</sub> = 100°C	I <sub>R</sub>	10 50	uA
Typical junction capacitance (Note 1)		C」	15	pF	

### THERMAL CHARACTERISTICS

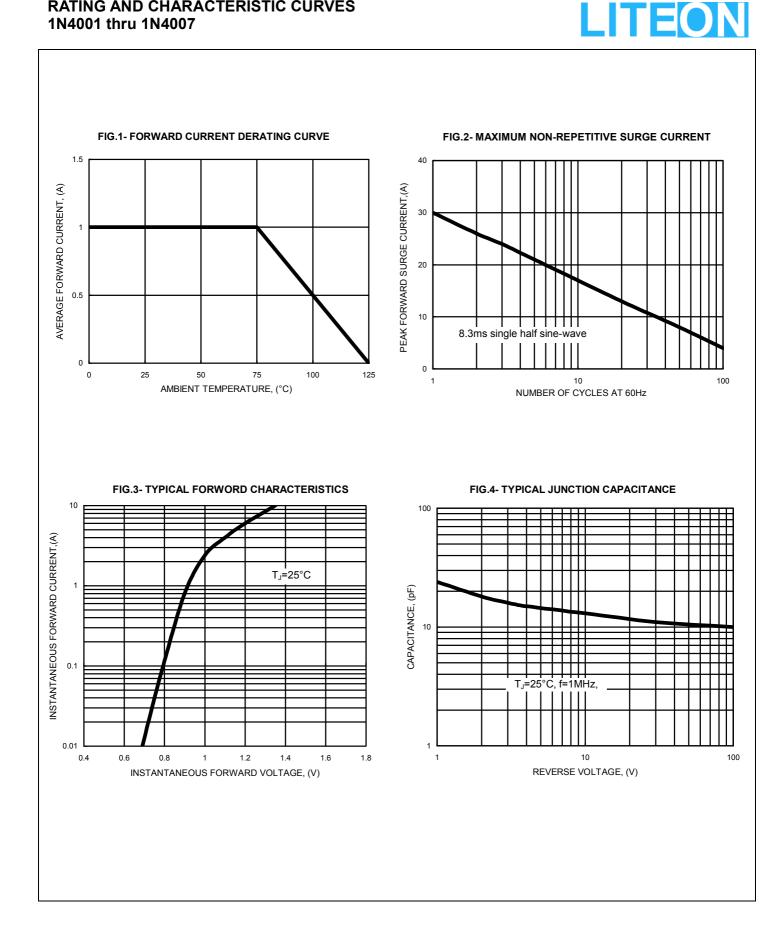
PARAMETER		SYMBOL	TYP.						
Thermal resistance (Note 2)		RthJ <sub>A</sub> RthJ <sub>C</sub>	50 12						
DYNAMIC ELECTRICAL CHARACTERISTICS									
PARAMETER	TEST CONDITION	SYMBOL	MIN.	MAX.	UNIT				
Reverse recovery time	IF= 0.5A, I <sub>RR</sub> = 0.25A, I <sub>R</sub> =1.0A	T <sub>RR</sub>	0.5	5.0	us				

#### Note :

(1) Measured at 1.0MHz and applied reverse voltage of 4.0V DC

(2) Thermal resistance junction to ambient and case,

## **RATING AND CHARACTERISTIC CURVES** 1N4001 thru 1N4007



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